

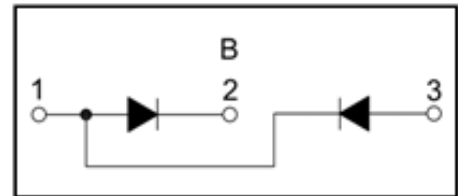
PRODUCT FEATURES

- Ultrafast Reverse Recovery Time
- Soft Reverse Recovery Characteristics
- Low Reverse Recovery Loss
- Low Forward Voltage
- High Surge Current Capability
- Low Inductance Package



APPLICATIONS

- Inversion Welder
- Uninterruptible Power Supply (UPS)
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- Power Factor Correction (PFC) Circuit



ABSOLUTE MAXIMUM RATINGS

T_C=25°C unless otherwise specified

Symbol	Parameter	Test Conditions	Values	Unit
V _R	Maximum D.C. Reverse Voltage		1700	V
V _{RRM}	Maximum Repetitive Reverse Voltage		1700	V
I _{F(AV)}	Average Forward Current	T _C =80°C, Per Diode	200	A
		T _C =80°C, 20KHz, Per Diode	150	A
I _{F(RMS)}	RMS Forward Current	T _C =80°C, Per Diode	280	A
I _{FSM}	Non-Repetitive Surge Forward Current	t=10ms, 50Hz, Sine	2000	A
		t=8.3ms, 60Hz, Sine	2200	A
I ² t	I ² t (For Fusing)	t=10ms, 50Hz, Sine	20000	A ² s
		t=8.3ms, 60Hz, Sine	24200	A ² s
P _D	Power Dissipation		893	W
T _J	Junction Temperature		-40 to +150	°C
T _{STG}	Storage Temperature Range		-40 to +125	°C
V _{isol}	Insulation Test Voltage	AC, t=1min	3000	V
Torque	Module-to-Sink	Recommended (M6)	3~5	N·m
Torque	Module Electrodes	Recommended (M6)	3~5	N·m
R _{θJC}	Thermal Resistance	Junction-to-Case	0.14	°C/W
Weight			160	g

ELECTRICAL CHARACTERISTICS

T_C=25°C unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I _{RM}	Reverse Leakage Current	V _R =1700V	--	--	5	mA
		V _R =1700V, T _J =125°C	--	--	20	mA
V _F	Forward Voltage	I _F =200A	--	1.8	2.25	V
		I _F =200A, T _J =125°C	--	1.95	--	V
t _{rr}	Reverse Recovery Time	I _F =1A, V _R =30V, di _F /dt=-200A/μs	--	120	--	ns
t _{rr}	Reverse Recovery Time	V _R =850V, I _F =200A	--	750	--	ns
I _{RRM}	Max. Reverse Recovery Current	di _F /dt=-200A/μs, T _J =25°C	--	40	--	A
t _{rr}	Reverse Recovery Time	V _R =850V, I _F =200A	--	1.4	--	μs
I _{RRM}	Max. Reverse Recovery Current	di _F /dt=-200A/μs, T _J =125°C	--	50	--	A
t _{rr}	Reverse Recovery Time	V _R =850V, I _F =200A	--	900	--	ns
I _{RRM}	Max. Reverse Recovery Current	di _F /dt=-1000A/μs, T _J =125°C	--	150	--	A

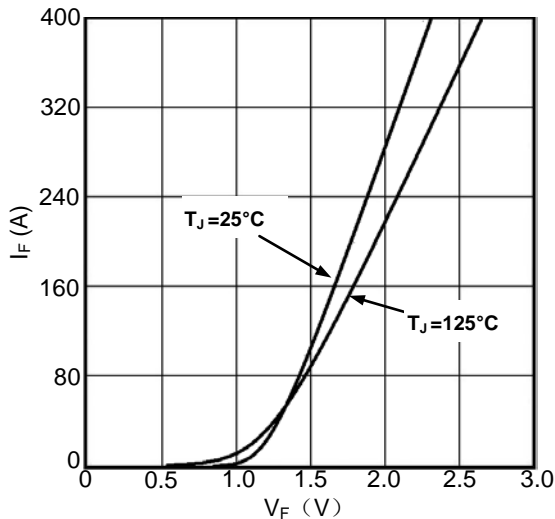


Figure1. Forward Voltage Drop vs Forward Current

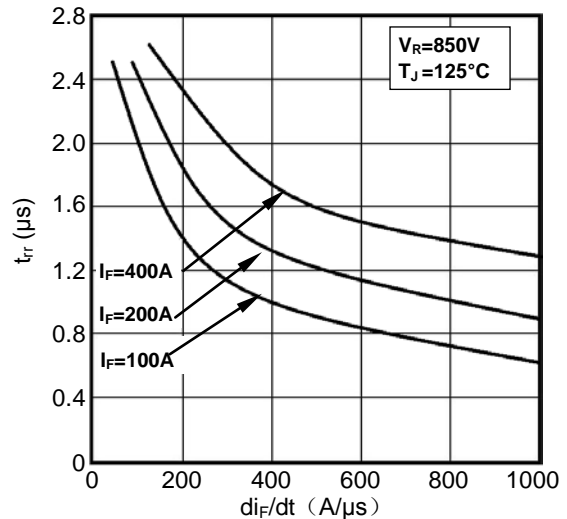


Figure2. Reverse Recovery Time vs di_F/dt

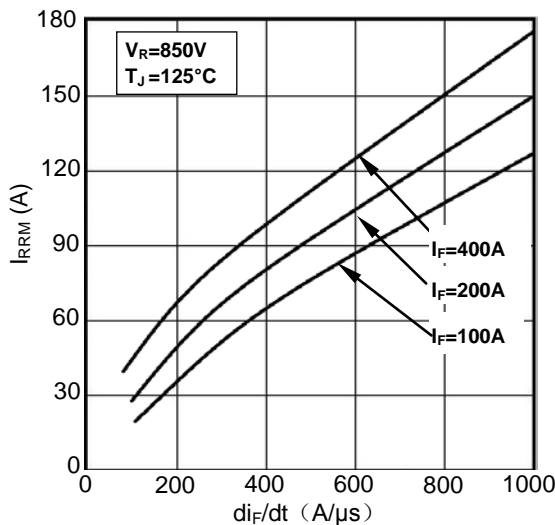


Figure3. Reverse Recovery Current vs di_F/dt

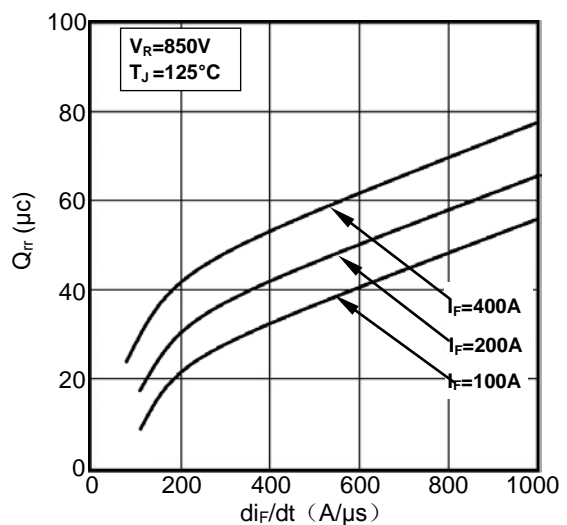


Figure4. Reverse Recovery Charge vs di_F/dt

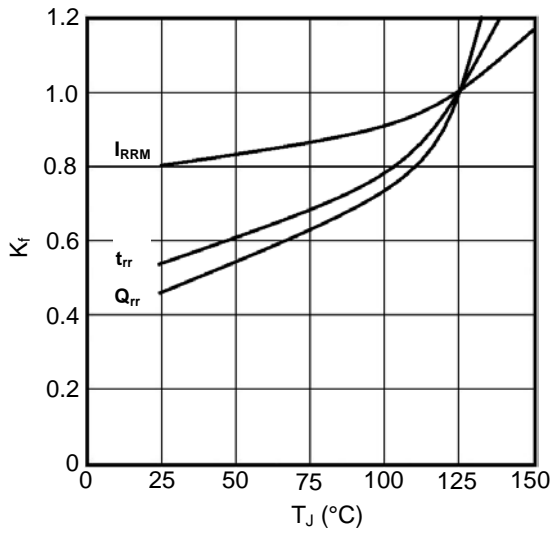


Figure5. Dynamic Parameters vs Junction Temperature

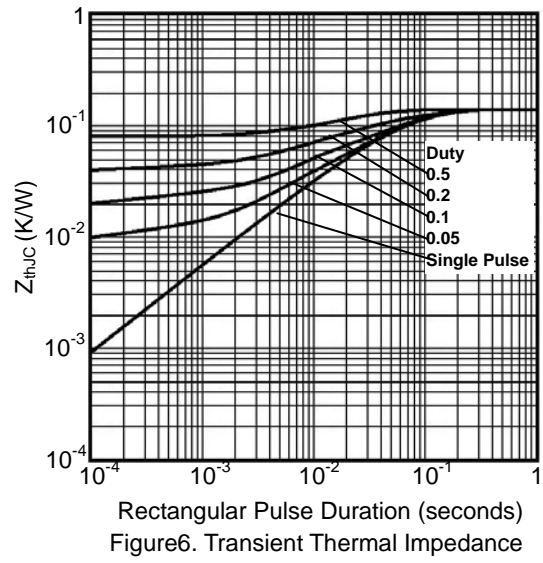
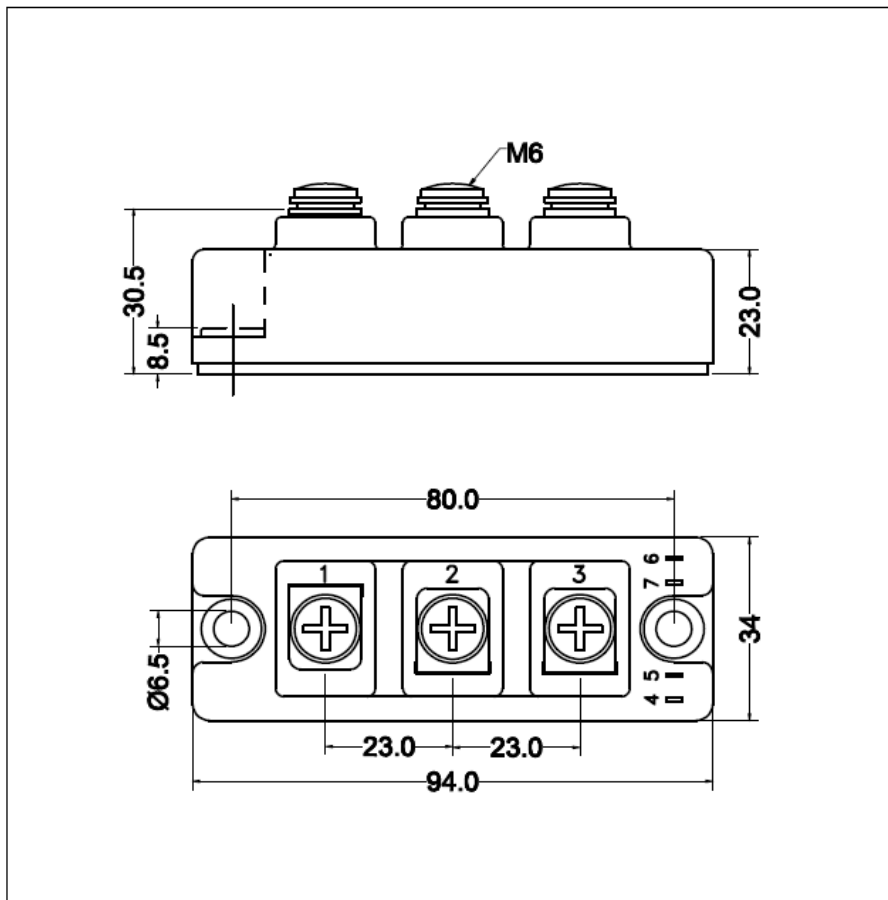


Figure6. Transient Thermal Impedance



Dimensions (mm)
Figure7. Package Outline